Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
0.142 inches
Overall Diameter:
0.063 inches
Mounting Method:
Press fit
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
1.0 forward voltage, dc and 100.0 breakdown voltage, dc
Current Rating Per Characteristic:
10.00 milliamperes source cutoff current preset and 5000.00 nanoamperes collector current, dc peak
Power Rating Per Characteristic:
500.0 milliwatts small-signal input power, common-collector preset
Capacitance Rating In Picofarads:
4.0
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius ambient air
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0